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| Form PTO-1449 (modified)  | Atty. Docket No.<br>2000.092182/TT5077                            | Serial No. 10/821230<br>Unknown |
| List of Patents and Publications for Applicant's<br>INFORMATION DISCLOSURE STATEMENT<br><br>(Use several sheets if necessary) | Applicant<br>Mark S. Fuselier, Derick J. Wristers and Andy C. Wei |                                 |
|   | Filing Date: 4/8/04<br>Concurrently Herewith                      | Group:<br>Unknown 5811          |
| U.S. Patent Documents<br>See Page 1   | Foreign Patent Documents<br>See Page 1                            | Other Art<br>See Page 1         |

### U.S. Patent Documents

| Exam. Init. | Ref. Des. | Document Number | Date    | Name                      | Class | Sub Class | Filing Date of App. |
|-------------|-----------|-----------------|---------|---------------------------|-------|-----------|---------------------|
| nm          | A1        | 5,482,871       | 01-1996 | Pollack                   | 438   | 151       |                     |
|             | A2        | 5,926,703       | 07-1999 | Yamaguchi <i>et al.</i>   | 438   | 163       |                     |
|             | A3        | 5,950,094       | 09-1999 | Lin <i>et al.</i>         | 438   | 409       |                     |
|             | A4        | 6,069,054       | 05-2000 | Choi                      | 438   | 423       |                     |
|             | A5        | 6,180,487       | 01-2001 | Lin                       | 438   | 407       |                     |
|             | A6        | 6,204,546       | 03-2001 | Roitman <i>et al.</i>     | 257   | 506       |                     |
|             | A7        | 6,232,163       | 05-2001 | Voldman <i>et al.</i>     | 438   | 212       |                     |
|             | A8        | 6,352,882       | 03-2002 | Assaderaghi <i>et al.</i> | 438   | 155       |                     |
|             | A9        | 6,407,428       | 06-2002 | Krishnan <i>et al.</i>    | 257   | 374       |                     |
|             | A10       | 6,531,375       | 03-2003 | Giewont <i>et al.</i>     | 438   | 407       |                     |

### Foreign Patent Documents

| Exam. Init. | Ref. Des. | Document Number | Date     | Country | Class | Sub Class | Translation Yes/No |
|-------------|-----------|-----------------|----------|---------|-------|-----------|--------------------|
| nm          | B1        | 0 687 002 A2    | 12/13/95 | Europe  | H01L  | 21/762    | Yes                |
| nm          | B2        | WO 00/48245     | 8/17/00  | PCT     | H01L  | 21/762    | Yes                |

### Other Art (Including Author, Title, Date Pertinent Pages, Etc.)

| Exam. Init. | Ref. Des. | Citation  |
|-------------|-----------|---|
| nm          | C1        | Baine <i>et al.</i> , "Back Gate Effects in N-Channel Monocrystalline Silicon Devices-on-Glass and Their Suppression by Boron Ion Implantation," <i>Mat. Res. Soc. Symp. Proc.</i> , 558:369-74, 2000 |
|             | C2        | Chang <i>et al.</i> , "Efficacy of Air in Reducing the Kink Effect on Floating-Body NFD/SOI CMOS," <i>Proc. 1998 IEEE Int'l SOI Conf.</i> , pp. 155-56, 1998  |
|             | C3        | Ko <i>et al.</i> , "Suppression of Floating Body Effect with SIGE Source Structure for Fully Depleted SOI MOSFET's," <i>Electrochem. Soc. Proc.</i> , 2001-3:239-44, 2001                             |
|             | C4        | Leung <i>et al.</i> , "High Voltage, High Speed Lateral IGBT in Thin SOI for Power IC," <i>Proc. 1996 IEEE Int'l SOI Conf.</i> , pp. 132-133, 1996  |

EXAMINER:

Kang, Donghee

DATE CONSIDERED:

01-03-05

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